2SA1531, 2SA1531A

Silicon PNP epitaxial planer type

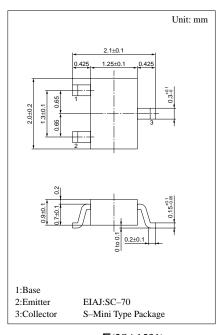
For low-frequency and low-noise amplification Complementary to 2SC3929 and 2SC3929A

Features

- Low noise voltage NV.
- High foward current transfer ratio h_{FE}.
- S-Mini type package, allowing downsizing of the equipment and automatic insertion through the tape packing and the magazine packing.

Absolute Maximum Ratings (Ta=25°C)

Parameter		Symbol	Ratings	Unit	
Collector to	2SA1531	37	-35	V	
base voltage	2SA1531A	V_{CBO}	-55		
Collector to	2SA1531	**	-35	V	
emitter voltage	2SA1531A	V_{CEO}	-55		
Emitter to base voltage		V_{EBO}	-5	V	
Peak collector current		I_{CP}	-100	mA	
Collector current		I_{C}	-50	mA	
Collector power dissipation		P_{C}	150	mW	
Junction temperature		T_{j}	150	°C	
Storage temperature		T_{stg}	−55 ~ +150	°C	



Marking symbol : F(2SA1531)H(2SA1531A)

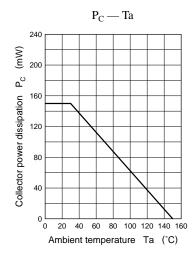
Electrical Characteristics (Ta=25°C)

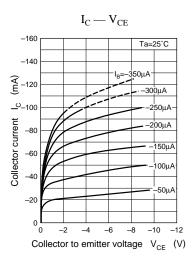
Parameter		Symbol	Conditions	min	typ	max	Unit
Collector cutoff current		I_{CBO}	$V_{CB} = -10V, I_E = 0$			-100	nA
		I_{CEO}	$V_{CE} = -10V, I_B = 0$			-1	μΑ
Collector to base	2SA1531		$I_{\rm C} = -10 \mu A, I_{\rm E} = 0$	-35			V
voltage	2SA1531A	V_{CBO}		-55			
Collector to emitter	2SA1531	**	$I_{\rm C} = -2mA, I_{\rm B} = 0$	-35			V
voltage	2SA1531A	V_{CEO}		-55			
Emitter to base voltage		V _{EBO}	$I_{\rm E} = -10\mu A, I_{\rm C} = 0$	-5			V
Forward current transfer ratio		h _{FE} *1	$V_{CE} = -5V, I_{C} = -2mA$	180		700	
Collector to emitter saturation voltage		V _{CE(sat)}	$I_C = -100 \text{mA}, I_B = -10 \text{mA}^{*2}$			- 0.6	V
		V _{BE}	$V_{CE} = -1V, I_C = -100 \text{mA}^{*2}$		- 0.7	-1.0	V
Transition frequency f _T		f_{T}	$V_{CB} = -10V$, $I_E = 2mA$, $f = 200MHz$		80		MHz
Noise voltage N		NV	$V_{CE} = -10V$, $I_{C} = -1$ mA, $G_{V} = 80$ dB $R_{g} = 100$ k Ω , Function = FLAT			150	mV

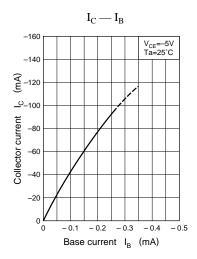
^{*1}h_{FE1} Rank classification

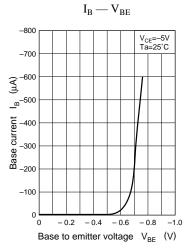
*2 Pulse measurement

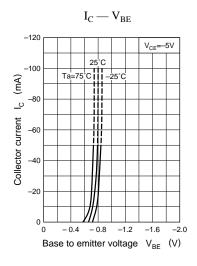
Rank R S T hFE 180 ~ 360 260 ~ 520 360 ~ 700 2SA1531 FR FS FT Marking Symbol 2SA1531A HR HS

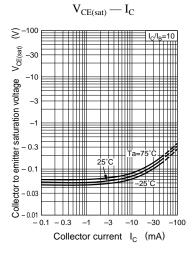


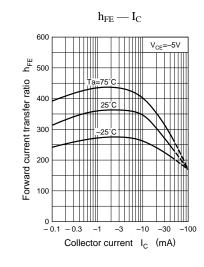


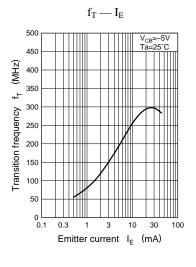


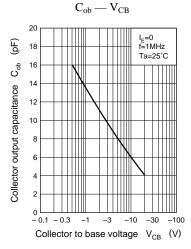










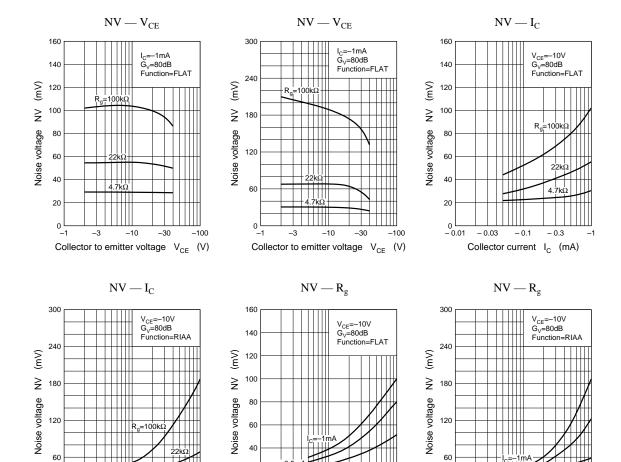


Signal source resistance R_g (k Ω)

0.01

-0.03

Collector current I_C (mA)



- 0.1m/

Signal source resistance $~{\rm R_g}~{\rm (k}\Omega)$

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